

NC7SZ157 TinyLogic[®] UHS 2-Input Non-Inverting Multiplexer

Features

- Broad V_{CC} Operating Range: 1.65V to 5.5V
- Ultra High-Speed
- Pow er Dow n High-Impedance Inputs/Outputs
- Over-Voltage Tolerance Inputs Facilitate 5V to 3V Translation
- Proprietary Noise/EMI Reduction Circuitry
- Ultra-Small MicroPak™ Packages
- Space-Saving SC70 Package

Description

The NC7SZ157 is a single, high performance, 2-to-1 CMOS non-inverting multiplexer from ON Semiconductor's Ultra-High Speed series of TinyLogic[®]. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static pow er dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and outputs are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 5.5V independent of V_{CC} operating range.

Ordering Information

Part Number	Top Mark	Eco Status	Package	Packing Method
NC7SZ157P6X	ZF7	RoHS	6-Lead SC70, EIAJ SC-88, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZ157L6X	B9	RoHS	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZ157FHX	B9	Green	6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel



Pin # SC70	Pin # MicroPak	Name	Description
1	1	h	Data Input
2	2	GND	Ground
3	3	lo	Data Input
4	4	Z	Output
5	5	Vcc	Supply Voltage
6	6	S	Control Input

Function Table

Inputs		Output		
I ₁	lo	$Z = (I_0) \bullet (S) + (I_1) \bullet (S)$		
Х	L	L		
Х	Н	Н		
L	Х	L		
Н	Х	Н		
	Inputs I1 X L H			

H = HIGH Logic Level

L = LOW Logic Level

X = Don'ť Care

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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Para	ameter	Min.	Max.	Unit
Vcc	Supply Voltage		-0.5	7.0	V
V _{IN}	DC Input Voltage		-0.5	7.0	V
Vout	DC Output Voltage	-0.5	7.0	V	
lıк	DC Input Diode Current	$V_{IN} \leq 0.5V$		-50	mA
Юк	DC Output Diode Current	$V_{OUT} \le -0.5V$		-50	mA
lout	DC Output Current		±50	mA	
Icc or Ignd	DC V _{CC} or Ground Current		±50	mA	
T _{STG}	Storage Temperature Range	-65	+150	°C	
TJ	Junction Temperature Under B	ias		+150	°C
TL	Junction Lead Temperature (Se	oldering, 10 Seconds)		+260	°C
		SC70-6		180	
PD	Pow er Dissipation at +85°C	MicroPak-6		130	mW
		MicroPak2-6		120	
FOD	Human Body Model, JEDEC: JE		4000	v	
ESD	Charge Device Model, JEDEC:	IESD22-C101		2000	v

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V _{CC}	Supply Voltage Operating		1.65	5.50	V
V CC	Supply Voltage Data Retention		1.50	5.50	v
V _{IN}	Input Voltage		0	5.5	V
Vout	Output Voltage		0	Vcc	V
TA	Operating Temperature		-40	+85	°C
		V _{CC} at 1.8V ± 0.15V, 2.5V ± 0.2V	0	20	
t _r , t _f	Input Rise and Fall Times	V _{CC} at 3.3V ± 0.3V	0	10	ns/V
		V _{CC} at 5.0V ± 0.5V	0	5	
		SC70-6		350	
θја	Thermal Resistance	MicroPak-6		500	°C/W
		MicroPak2-6		560	

Curren la a l	Denemator	V	O an all the ma		T _A =+25°C			T _A =-40 to +85°C			
Symbol	Parameter	V _{CC} Conditio		altions	Min.	Тур.	Max.	Min.	Max.	Units	
	HIGH Level Input	1.65 to 1.95			$0.75V_{\text{CC}}$			$0.75V_{\text{CC}}$		V	
V _{IH} Voltage		2.30 to 5.50			$0.70V_{\text{CC}}$			$0.70V_{\text{CC}}$		V	
V	LOW Level Input	1.65 to 1.95					$0.25V_{CC}$		$0.25V_{CC}$	V	
VIL	Voltage	2.30 to 5.50					$0.30V_{CC}$		$0.30V_{CC}$	v	
		1.65			1.55	1.65		1.55			
		2.30	V _{IN} =V _{IL}	I _{он} = -100µА	2.20	2.30		2.20			
V _{он} HIGH Lev Output Vo		3.00	or V _{IH}	10H= -100µA	2.90	3.00		2.90			
		4.50			4.40	4.50		4.40			
	HIGH Level Output Voltage	1.65	V _{IN} =V _{IL} or V _{IH}	I _{он} = -4mA	1.29	1.52		1.29		V	
		2.30		I _{он} = -8mA	1.90	2.15		1.90			
		3.00		I _{он} = -16mA	2.40	2.80		2.40			
		3.00		I _{он} = -24mA	2.30	3.68		2.30			
		4.50		I _{он} = -32mA	3.90	4.20		3.80			
		1.65	V _{IN} =V _{IL}	I _{ol} = 100μΑ		0	0.10		0.10	V	
		2.30				0	0.10		0.10		
		3.00	or V_{IH}			0	0.10		0.10		
		4.50				0	0.10		0.10		
V_{OL}	LOW Level Output Voltage	1.65		I _{OL} = 4mA		0.08	0.24		0.24		
	1 0	2.30	V _{IN} =V _{IL}	I _{OL} = 8mA		0.10	0.30		0.30		
		3.00	or V _{IH}	I _{OL} = 16mA		0.15	0.40		0.40	V	
		3.00		I _{OL} = 24mA		0.22	0.55		0.55		
		4.5		I _{OL} = 32mA		0.22	0.55		0.55		
I _{IN}	Input Leakage Current	0 to 5.50	V _{IN} =5.5V, GND				±0.1		±1	μA	
I _{OFF}	Power Off Leakage Current	0	V _{IN} or V _{OUT} =5.5V				1		10	μA	
Icc	Quiescent Supply Current	1.65 to 5.50	V _{IN} =5.5	/, GND					10	μA	

Sym bol	Parameter	V _{cc}	Conditions	T _A =+25°C		T _A =-40 to +85°C		L ha it a	Figure	
	Farameter			Min.	Тур.	Max.	Min.	Max.	Units	Figure
		1.80 ± 0.15		2.5	6.0	11.5	2.5	12.0		
	Propagation Delay S to Z	2.50 ± 0.20	oL=ropr,	1.2	3.5	6.1	1.2	6.5		
		3.30 ± 0.30		0.8	2.6	4.1	0.8	4.5		
	5.00 ± 0.50		0.5	1.9	3.2	0.5	3.5	1		
	Propagation Delay	1.80 ± 0.15	C∟=15pF, R∟=1MΩ,	2.5	5.9	10.0	2.5	10.5	ns	Figure 5 Figure 6
		5.00 ± 0.50		1.2	3.5	5.8	1.2	6.1		
t _{PLH} , t _{PHL}	I _n to Z	3.30 ± 0.30		0.8	2.6	3.9	0.8	4.2		
		5.00 ± 0.50		0.5	1.9	3.1	0.5	3.3		
	Propagation Delay	3.30 ± 0.30	C _L =50pF,	1.2	3.2	4.8	1.2	5.2		
	S to Z	5.00 ± 0.50	R∟=500Ω,	0.8	2.4	3.8	0.8	4.1		
	Propagation Delay	3.30 ± 0.30	C∟=50pF,	1.2	3.2	4.6	1.2	5.0		
	I _n to Z	5.00 ± 0.50	R _L =500Ω,	0.8	2.4	3.7	0.8	4.0		
CIN	Input Capacitance	0.00			2				pF	
C _{PD}	Power Dissipation	3.30			14				ъĒ	Figure
CPD	Capacitance ⁽⁴⁾	5.00			17				рF	Figure 7

Note:

4. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD}=(C_{PD})(V_{CC})(f_{IN})+(I_{CC}static).







5. C_L includes load and stray capacitance. Input PRR=1.0MHz, t_w=500ns.



Figure 6. AC Waveforms



Note:

6. Input=AC Waveform; PRR=Variable; Duty Cycle=50%.

Figure 7. I_{CCD} Test Circuit





Package drawings are provided as a service to customers considering ON Semiconductor components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a ON Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of ON Semiconductor's worldwide terms and conditions, specifically the warranty therein, which covers ON Semiconductor products.

Tape and Reel Specifications

Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status	
	Leader (Start End)	125 (Typical)	Empty	Sealed	
P6X	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (Typical)	Empty	Sealed	



Tape and Reel Specifications

Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
	Leader (Start End)	125 (Typical)	Empty	Sealed
L6X	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed



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Tape and Reel Specifications

Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
	Leader (Start End)	125 (Typical)	Empty	Sealed
FHX	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed

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